MM54HC390, MM74HC390 / MM54HC393, MM74HC393

Dual 4-Bit Decade Counter / Dual 4-Bit Binary Counter

These counter circuits contain independent ripple carry counters and utilize advanced silicon-gate CMOS technology. The MM54HC390/MM74HC390 incorporate dual decade counters, each composed of a divide-by-two and a divide-by-five counter. The divide-by-two and divide-by-five counters can be cascaded to form dual decade, dual bi-quinary, or various combinations up to a single divide-by-100 counter. The MM54HC393/MM74HC393 contain two 4-bit ripple carry binary counters, which can be cascaded to create a single divide-by-256 counter.

Each of the two 4-bit counters is incremented on the high to low transition (negative edge) of the clock input, and each has an independent clear input. When clear is set high all four bits of each counter are set to a low level. This enables count truncation and allows the implementation of divide-by-N counter configurations.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

National Semiconductor

T-45-23-13

MM54HC390/MM74HC390 Dual 4-Bit Decade Counter MM54HC393/MM74HC393 Dual 4-Bit Binary Counter

General Description

These counter circuits contain independent ripple carry counters and utilize advanced silicon-gate CMOS technology. The MM54HC390/MM74HC390 incorporate dual decade counters, each composed of a divide-by-two and a divide-by-five counter. The divide-by-two and divide-by-five counters can be cascaded to form dual decade, dual bi-quinary, or various combinations up to a single divide-by-100 counter. The MM54HC393/MM74HC393 contain two 4-bit ripple carry binary counters, which can be cascaded to create a single divide-by-256 counter.

Each of the two 4-bit counters is incremented on the high to low transition (negative edge) of the clock input, and each has an independent clear input. When clear is set high all four bits of each counter are set to a low level. This enables count truncation and allows the implementation of divide-by-N counter configurations.

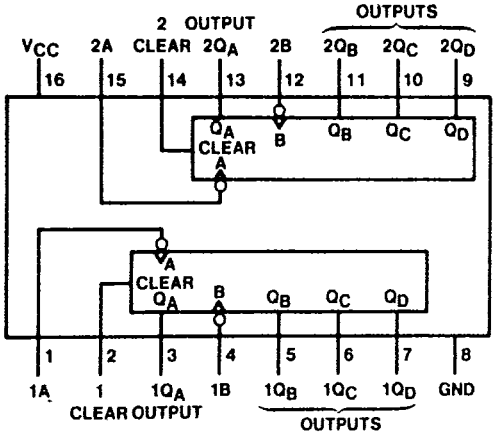
Each of the counters outputs can drive 10 low power Schottky TTL equivalent loads. These counters are functionally as well as pin equivalent to the 54LS390/74LS390 and the 54LS393/74LS393, respectively. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical operating frequency: 50 MHz
- Typical propagation delay: 13 ns (Ck to Q_A)
- Wide operating supply voltage range: 2–6V
- Low input current: <1 μA
- Low quiescent supply current: 80 μA maximum (74HC Series)
- Fanout of 10 LS-TTL loads

Connection Diagrams

Dual-In-Line Package



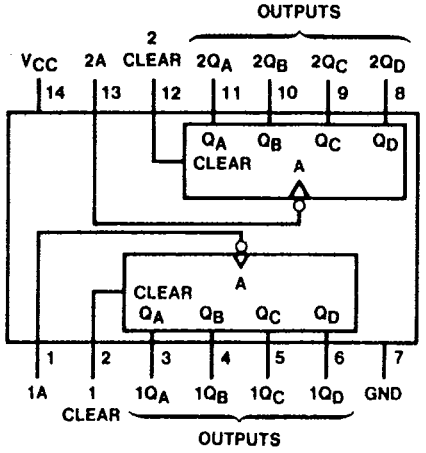
TL/F/5337–1

Top View

Order Number MM54HC390* or MM74HC390*

*Please look into Section 8, Appendix D for availability of various package types.

Dual-In-Line Package



TL/F/5337–2

Top View

Order Number MM54HC393* or MM74HC393*

*Please look into Section 8, Appendix D for availability of various package types.

T-45-23-13

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC}+1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC}+0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	−40	+85	°C
MM54HC	−55	+125	°C
Input Rise or Fall Times (t_r, t_f) V_{CC}=2.0V		1000	ns
V_{CC}=4.5V		500	ns
V_{CC}=6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A=25°C	74HC T_A=−40 to 85°C	54HC T_A=−55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum High Level Output Voltage	$V_{IN}=V_{IH}$ or V_{IL} $\|I_{OUT}\|\leq 20\ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN}=V_{IH}$ or V_{IL} $\|I_{OUT}\|\leq 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\|\leq 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum Low Level Output Voltage	$V_{IN}=V_{IH}$ or V_{IL} $\|I_{OUT}\|\leq 20\ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN}=V_{IH}$ or V_{IL} $\|I_{OUT}\|\leq 4.0$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\|\leq 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	$V_{IN}=V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{IN}=V_{CC}$ or GND $I_{OUT}=0\ \mu A$	6.0V		8.0	80	160	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

**V_{IL} limits are currently tested at 20% of V_{CC}. The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

T-45-23-13

AC Electrical Characteristics MM54HC390/MM74HC390

$V_{CC}=5V$, $T_A=25°C$, $C_L=15$ pF, $t_r=t_f=6$ ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency, Clock A or B		50	30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_A Output		12	20	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_C (Q_A Connected to Clock B)		32	50	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock B to Q_B or Q_D		15	21	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock B to Q_C		20	32	ns
t_{PHL}	Maximum Propagation Delay, Clear to any Output		15	28	ns
t_{REM}	Minimum Removal Time, Clear to Clock		−2	5	ns
t_W	Minimum Pulse Width, Clear or Clock		10	16	ns

AC Electrical Characteristics $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$	74HC $T_A=-40$ to $85°C$	54HC $T_A=-55$ to $125°C$	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V		5	4	3	MHz
			4.5V		27	21	18	MHz
			6.0V		31	24	20	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_A		2.0V	45	120	150	180	ns
			4.5V	15	24	30	35	ns
			6.0V	13	21	26	31	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_C (Q_A Connected to Clock B)		2.0V	100	290	360	430	ns
			4.5V	35	58	72	87	ns
			6.0V	30	50	62	75	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock B to Q_B or Q_D		2.0V	50	130	160	195	ns
			4.5V	16	26	33	39	ns
			6.0V	13	22	28	33	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock B to Q_C		2.0V	60	185	230	280	ns
			4.5V	20	37	46	55	ns
			6.0V	17	32	40	48	ns
t_{PHL}	Maximum Propagation Delay, Clear to any Q		2.0V	55	165	210	250	ns
			4.5V	17	33	41	49	ns
			6.0V	15	28	35	42	ns
t_{REM}	Minimum Removal Time Clear to Clock		2.0V		25	25	25	ns
			4.5V		5	5	5	ns
			6.0V		5	5	5	ns
t_W	Minimum Pulse Width Clear or Clock		2.0V	30	80	100	120	ns
			4.5V	10	16	20	24	ns
			6.0V	9	14	18	20	ns
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
t_r, t_f	Maximum Input Rise and Fall Time		2.0V		1000	1000	1000	ns
			4.5V		500	500	500	ns
			6.0V		400	400	400	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per counter)		55				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}\,V_{CC}^2\,f+I_{CC}\,V_{CC}$, and the no load dynamic current consumption, $I_S=C_{PD}\,V_{CC}\,f+I_{CC}$.

3

T-45-23-13

AC Electrical Characteristics MM54HC393/MM74HC393

$V_{CC}=5V$, $T_A=25°C$, $C_L=15$ pF, $t_r=t_f=6$ ns

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency		50	30	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_A		13	20	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_B		19	35	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_C		23	42	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock A to Q_D		27	50	ns
t_{PHL}	Maximum Propagation Delay, Clear to any Q		15	28	ns
t_{REM}	Minimum Removal Time		−2	5	ns
t_W	Minimum Pulse Width Clear or Clock		10	16	ns

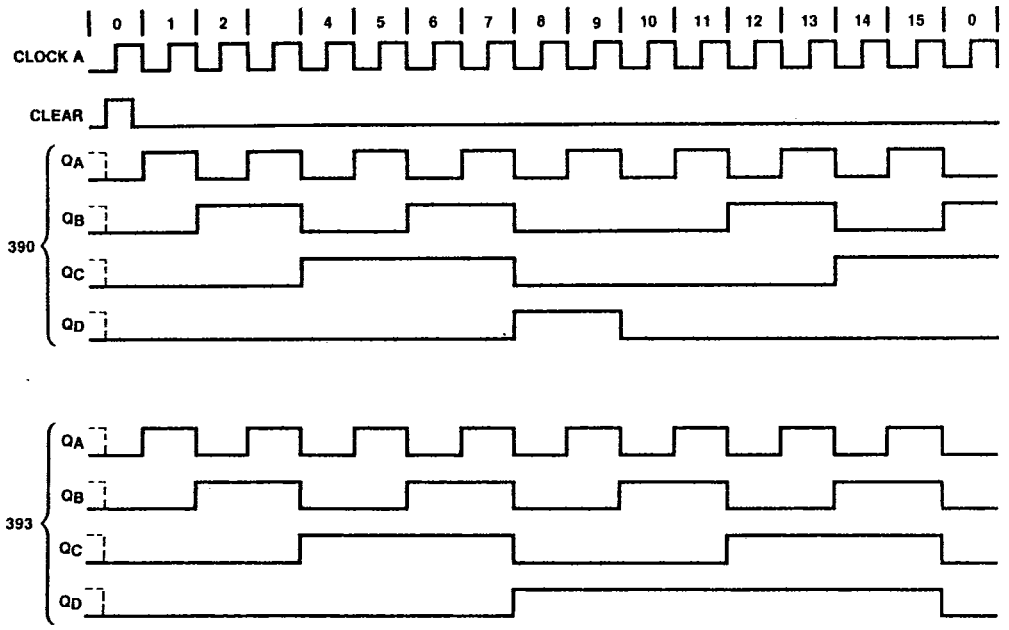
AC Electrical Characteristics $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$	74HC $T_A=-40$ to 85°C	54HC $T_A=-55$ to 125°C	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V	5	4	3	
			4.5V	27	21	18	MHz
			6.0V	31	24	20	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock A to Q_A		2.0V	45	120	150	180	ns
			4.5V	15	24	30	35	ns
			6.0V	13	21	26	31	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock A to Q_B		2.0V	68	190	240	285	ns
			4.5V	23	38	47	57	ns
			6.0V	20	32	40	48	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock A to Q_C		2.0V	90	240	300	360	ns
			4.5V	30	48	60	72	ns
			6.0V	26	41	51	61	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay Clock to Q_D		2.0V	100	290	360	430	ns
			4.5V	35	58	72	87	ns
			6.0V	30	50	62	75	ns
t_{PHL}	Maximum Propagation Delay Clear to any Q		2.0V	54	165	210	250	ns
			4.5V	18	33	41	49	ns
			6.0V	15	28	35	42	ns
t_{REM}	Minimum Clear Removal Time		2.0V		25	25	25	ns
			4.5V		5	5	5	ns
			6.0V		5	5	5	ns
t_W	Minimum Pulse Width Clear or Clock		2.0V	30	80	100	120	ns
			4.5V	10	16	20	24	ns
			6.0V	9	14	18	20	ns
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time		2.0V	30	75	95	110	ns
			4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
t_r, t_f	Maximum Input Rise and Fall Time				1000	1000	1000	ns
					500	500	500	ns
					400	400	400	ns
C_{PD}	Power Dissipation Capacitance (Note 5)	(per counter)		42				pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D=C_{PD}V_{CC}^2 f+I_{CC}V_{CC}$, and the no load dynamic current consumption, $I_S=C_{PD}V_{CC}f+I_{CC}$.

Logic Timing Waveforms

T-45-23-13



TL/F/5337–3